

INFRARED EMITTING DIODES

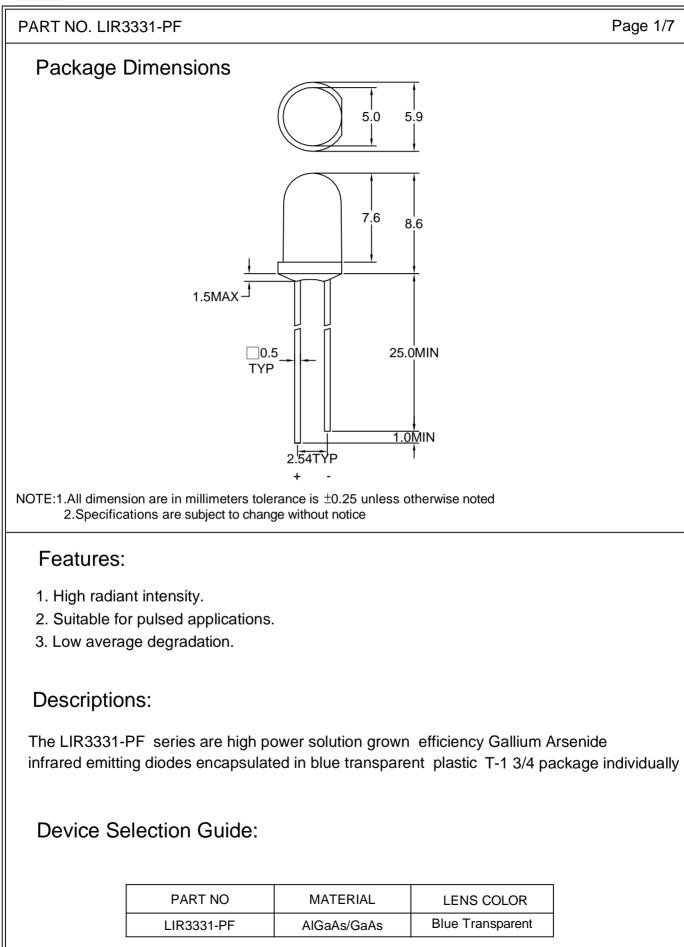


## LIR3331-PF

# DATA SHEET

DOC. NO :		QW0905-LIR3331-PF			
REV.		В			
DATE	:	29 - Mar 2007			







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## Absolute Maximum Ratings at Ta=25 $^\circ\!\mathrm{C}$

Parameter	Symbol	Ratings	UNIT
Farameter	Gymbol	IR	
Forward Current	lF	50	mA
Peak Forward Current (300PPS,10 μ s Pulse)	IFP	1	А
Power Dissipation	PD	100	mW
Reverse Voltage	Vr	5	V
Electrostatic Discharge	ESD	2000	V
Operating Temperature	Topr	-40 ~ +85	°C
Storage Temperature	Tstg	-40 ~ +85	°C

## Electrical Optical Characteristics (Aa=25°C)

PARAMETER	SYMBOL	Min.	Тур.	Max.	UNIT	TEST CONDITION
Radiant Intensity	Le	6.0	10.0		mW/sr	IF=20mA
Aperture Radiant Incidence	Ee	0.9	1.4		mW/cm <sup>2</sup>	IF=20mA
Peak Emission Wavelength	$\lambda$ peak		940		nm	IF=20mA
Spectral Line Half Width	$\bigtriangleup \lambda$		50		nm	IF=20mA
Forward Voltage (@ 40 ms)	VF		1.2	1.6	V	IF=20mA
Reverse Current	IR			100	$\mu$ A	VR=5V
Viewing Angle	2 <i>θ</i> 1/2		20		deg	

Note : 1. The forward voltage data did not including  $\pm 0.1V$  testing tolerance.

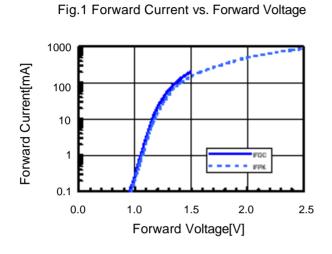
2. The radiant intensity data did not including  $\pm 15\%$  testing tolerance.



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## Typical Electro-Optical Characteristics Curve

#### **IR CHIP**



#### Fig.3 Relative Radiant Power vs. Forward DC Current

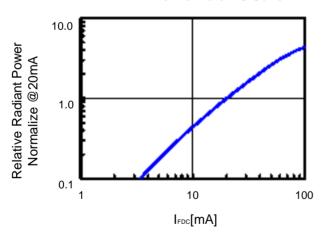


Fig.5 Forward DC Voltage vs. Temperature

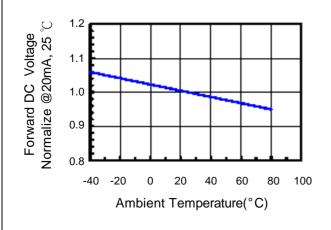
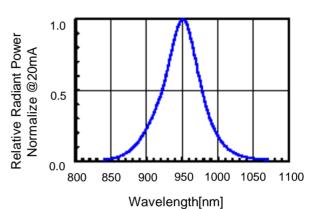
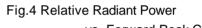
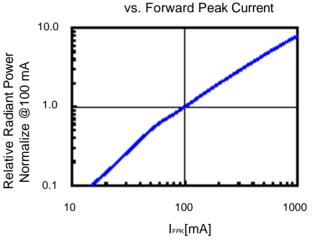


Fig.2 Relative Radiant Power vs. Wavelength

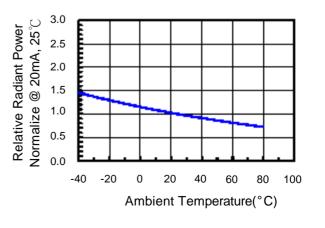
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#### Storage time:

- 1.The operation of Temperatures and RH are : 5  $^\circ\!\mathrm{C}$  ~35  $^\circ\!\mathrm{C}$  ,RH<60%.
- 2.Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp proof box with descanting agent. Considering the tape life, we suggest our customers to use our products within a year(from production date).
- 3.If opened more than one week in an atmosphere 5  $^{\circ}$ C ~ 35  $^{\circ}$ C ,RH<60%, they should be treated at 60  $^{\circ}$ C ±5  $^{\circ}$ C fo r 15hrs.

#### Drive Method:

LED is a current operated device, and therefore, require some kind of current limiting incorporated into the driver circuit. This current limiting typically takes the form of a current limiting resistor placed in series with the LED.

Consider worst case voltage variations than could occur across the current limiting resistor. The forwrd current should not be allowed to change by more than 40 % of its desired value.



(A) Recommended circuit.

(B) The difference of brightness between LED could be found due to the VF-IF characteristics of LED.

### **Cleaning:**

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED.

### ESD(Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing these LED. All devices, equipment and machinery must be properly grounded.

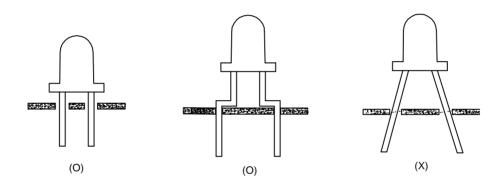


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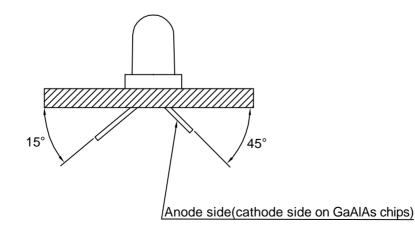
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#### Mounting:

 If the leads are subjected to stress during soldering a printed circuit board, illumination failure may result immediately or later during use. For this reason, make sure that the intervals between the installation holes in the board are equal to the intervals between the leads (after forming if done) so that no stress is applied to the lead.



2. The LED lamps are designed for high-density mounting and have a structure which can alleviate mechanical stress due to clinching. Nevertheless, take care to avoid the occurrence of residual mechanical stress due to clinching.





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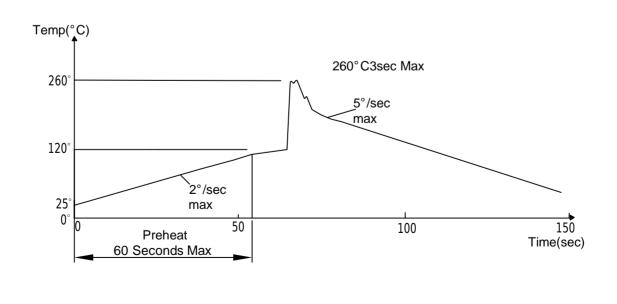
#### Soldering Condition(Pb-Free)

#### 1.Iron:

Soldering Iron:30W Max Temperature 350°C Max Soldering Time:3 Seconds Max(One time only) Distance:2mm Min(From solder joint to body)

#### 2. Wave Soldering Profile

Dip Soldering Preheat: 120°C Max Preheat time: 60seconds Max Ramp-up 2°C/sec(max) Ramp-Down:-5°C/sec(max) Solder Bath:260°C Max Dipping Time:3 seconds Max Distance:2mm Min(From solder joint to body)



Note: 1.Wave solder should not be made more than one time. 2.You can just only select one of the soldering conditions as above.



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MIL-STD-750: 1051

MIL-STD-883: 1011

MIL-STD-202: 210A

MIL-STD-750: 2031

JIS C 7021: A-1

MIL-STD-202: 208D

MIL-STD-750: 2026

MIL-STD-883: 2003 JIS C 7021: A-2

#### Re

Thermal Shock Test

Solder Resistance

Test

Solderability Test

eliability Tes	t:		
			Γ
Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=20mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of detemining the resistance of a part in electrical and themal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=85 ℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40 °C±5 °C 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65 ℃ ±5 ℃ 2.RH=90 %~95 % 3.t=240hrs ±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11
	1.Ta=105 ℃±5℃ &-40℃±5℃	The purpose of this is the resistance of	MIL-STD-202: 107D

the device to sudden extreme changes

This test intended to determine the thermal characteristic resistance

of the device to sudden exposures

at extreme changes in temperature

This test intended to see soldering well

when soldering the lead wire.

performed or not.

in high and low temperature.

(10min) (10min)

1.T.Sol=260 °C±5°C

1.T.Sol=230 ℃±5℃

2.Dwell time=5 ±1sec

2.Dwell time= 10 ±1sec.

2.total 10 cycles